

## Circuit for protecting low-voltage SAR ADC from electrical overstress with minimal impact on performance

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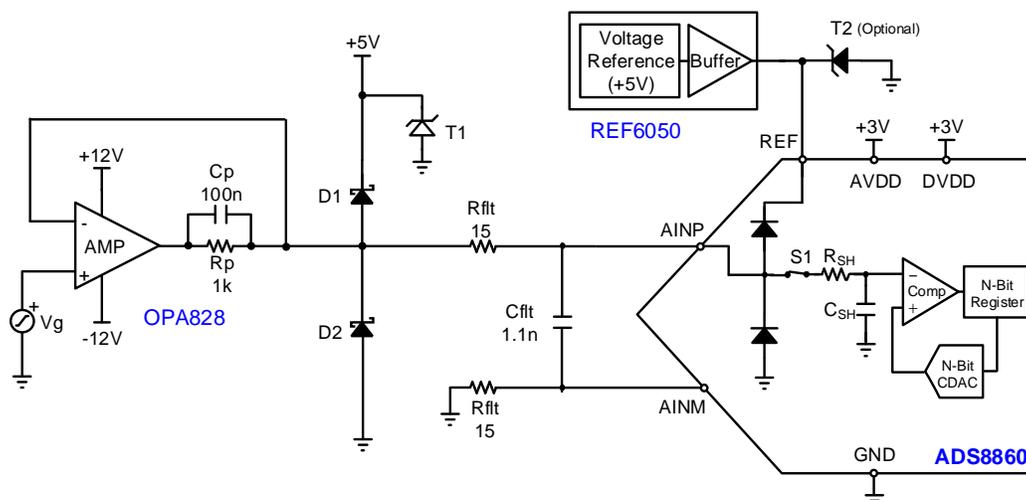
Single-Ended Input ( $V_{REF} = +5V$ )	ADC Input	Digital Output ADS8860
$V_{inMax} = +5V$	$AINP = +5V, AINN = 0V$	$FFFF_H$
$V_{inMin} = 0V$	$AINP = 0V, AINN = 0V$	$0000_H$

Power Supplies and Reference			
Vcc on OPA828	Vee on OPA828	Clamp Voltage and Reference	ADS8860 AVDD and DVDD
+12V	-12V	+5V	+3V

### Design Description

This cookbook circuit describes how to connect a high-voltage amplifier (for example,  $\pm 12V$ ) to a low voltage ADC (for example, 0V to 5V) and clamp the output voltage of the amplifier to protect the ADC from electrical overstress damage. Furthermore, this document shows the impact that the protection clamp has on system performance. This circuit is useful in [test and measurement](#), and [factory automation and control](#).

This example circuit connects the [OPA828](#) to the [ADS8860](#). The OPA828 device has  $\pm 12V$  supplies and the ADS8860 device has 0-V to 5-V input range. Normally, the amplifier supplies are matched to the ADC input range to prevent overstress of the inputs, but in some cases it may be useful to connect a higher voltage amplifier to a low-voltage ADC. Under a fault condition, when the output of the amplifier is above 5V or below ground, the diodes D1 and D2 turn on and limit the ADC input voltage to safe levels. The resistor  $R_p$  limits the output current under fault conditions. The  $R_p$  resistor is connected inside the amplifier feedback so that the impedance is reduced by the amplifiers feedback, under normal conditions. Keeping  $R_p$  in the feedback improves AC system performance (SNR and THD). This protection method is suitable for other precision SAR ADC with a switched capacitor input.



## Specifications

Specification	Goal	Calculated	Simulated	Measured
Transient Settling Error	< 1/2LSB (< 38.15 $\mu$ V)		0.3 LSB (23.1 $\mu$ V)	
THD	< -108dB			-113.7dB
SNR	> 92dB			93.3dB
Bandwidth	> 1MHz	4.82MHz	5.08MHz	
Noise	< 1/2LSB (< 38.15 $\mu$ V)	11.3 $\mu$ V <sub>RMS</sub>	10.04 $\mu$ V <sub>RMS</sub>	

## Design Notes

1. The BAT54 diode is selected for D1 and D2 because of its lower forward voltage, low leakage current, and low capacitance as the capacitance on the diode is nonlinear and can introduce distortion.
2. The OPA828 device is a high bandwidth (45MHz) precision amplifier which is good enough to drive the 16-bit precision SAR ADC ADS8860 device. See the *TI Precision Labs – ADCs* training video: [Introduction of Selecting and Verifying the Driver Amplifier](#), for details.
3. Select the COG type capacitor for C<sub>fit</sub> to minimize the distortion.

## Component Selection

- The following table lists the maximum output voltage and current for the OPA828 amplifier. The table also lists the absolute maximum specifications for the ADS8860 ADC. The ADC input voltage range is set as the maximum voltage before turning on the internal ESD diodes. The input current range is the maximum current the internal ESD diodes can support continuously.

OPA828 Output		ADS8860 Absolute Maximum Ratings		
OPA828 maximum output voltage: (EOS voltage range - $V_o$ )	$-12V \leq V_o < 0V$	AINP or AINN to GND	-0.3V	$V_{ADC\_in\_min}$
	$+5V < V_o \leq +12V$		+5.3V	$V_{ADC\_in\_max}$
OPA828 maximum output current: (Short-circuit current - $I_{sc}$ )	-50mA	Input current	-10mA	$I_{ADC\_in\_min}$
	+50mA		+10mA	$I_{ADC\_in\_max}$

- Select a diode with a low forward drop, low leakage current, sufficient forward current, and low capacitance. Generally, a Schottky diode is used for its low forward drop. See the video series on [EOS Protection for ADCs](#) for details on selection of the diode and other information on overstress protection. In this example, the BAT54 Schottky diode is selected as it has a good forward voltage drop as well reasonable leakage current and capacitance. The BAT54 is a common choice for EOS protection.
- For this circuit, a -12-V output from the OPA828 amplifier is limited to -0.42V, and a 12-V output is limited to 5.42V. The largest voltage across  $R_p$  occurs when the amplifier output is at -12V. Hence,  $R_p$  is determined by the following equation:

$$R_p > \frac{V_{fD2} - V_{oNegMax}}{I_{fault}} = \frac{-0.42V - (-12V)}{15mA} > 772\Omega \text{ (round up to } 1k\Omega)$$

- In the following equation, the fault current and power dissipated is calculated in  $R_p$  during an electrical overstress fault event. The objective is to make sure that the correct power rating is used on the resistor  $R_p$ .

$$I_{fault} = \frac{V_{fD2} - V_{oNegMax}}{R_p} = \frac{-0.42V - (-12V)}{1k\Omega} = 11.6mA$$

$$P_{Rp} = (I_{fault})^2 R_p = (11.6mA)^2 (1k\Omega) = 134mW \text{ (use } 0.2W \text{ for margin)}$$

- The resistor  $R_{flt}$  acts as a charge bucket filter and also to limit the current under a fault condition. First, a minimum value of  $R_{flt}$  is determined for fault protection by assuming D2 has a 0.42-V drop on it and the internal ESD diode has 0.3V on it. Using this voltage and the absolute maximum input current rating, the minimum value of  $R_{flt}$  for current limiting is selected (12 $\Omega$ ).

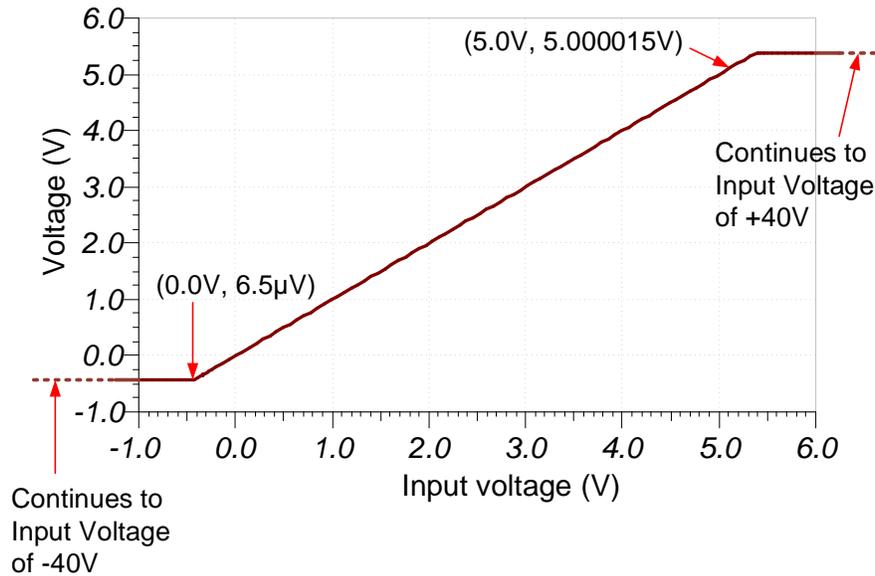
$$R_{flt} > \frac{V_{ADC\_in\_min} - V_{fD2}}{I_{ADC\_in\_max}} = \frac{-0.3V - (-0.42V)}{10mA} > 12\Omega$$

- Next, a [TINA SPICE](#) optimization is performed on  $R_{flt}$  and  $C_{flt}$  to get the best settling. For this optimization the minimum value of  $R_{flt}$  is set to 12 $\Omega$  for input protection (see step 5). The final value for the (15 $\Omega$ ) and (1.1nF) in the charge bucket circuit are optimized and selected for the best signal settling and AC performance. See the methods described in [SAR ADC Front-End Component Selection](#) for details.
- The capacitor  $C_p$  in parallel with  $R_p$  is used to reduce the AC impedance of the protection network ( $R_p || C_p$ ) at higher frequencies. This value may impact the stability of the design as well. The idea is to set the cutoff frequency of the network to be much lower than the amplifier cutoff. The exact value may not be very critical so here we round to a common standard value of 100nF. Also, note that we confirm stability later in this document.

$$C_p \approx \frac{1}{2\pi R_p f} = \frac{1}{2\pi (1k\Omega)(1kHz)} > 159nF \text{ (choose } 100nF \text{ and check stability)}$$

### DC Transfer Characteristics

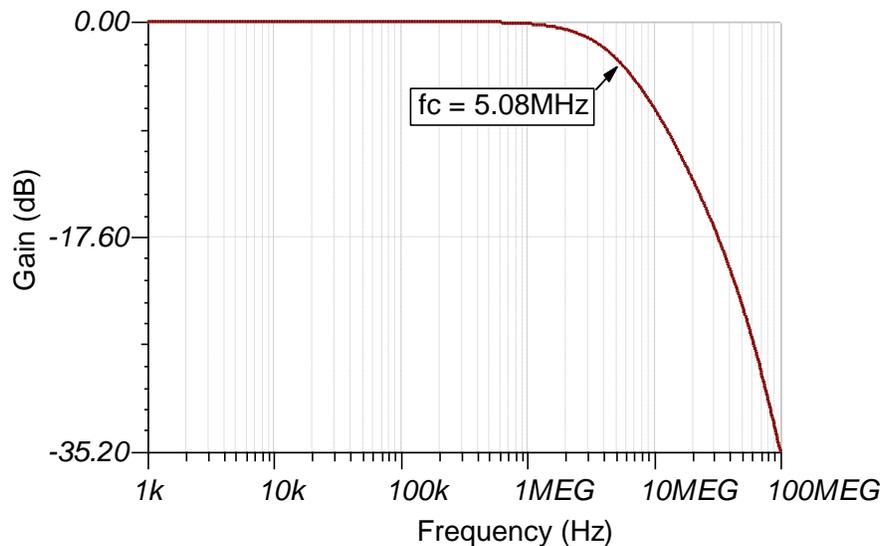
The following graph shows a linear output response for inputs from single-ended -40V to +40V. See [Determining a SAR ADC's Linear Range when using Operational Amplifiers](#) for detailed theory on this subject. Note that the output range is intentionally limited to -0.42V to 5.38V using Schottky diodes to protect the ADS8860 device. Note that Schottky diodes are used because the low forward voltage drop (typically less than 0.3V) keeps the output limit very near the ADC supply voltages. The absolute maximum rating for the ADS8860 is  $-0.3V < V_{in} < REF + 0.3V$ .



### AC Transfer Characteristics

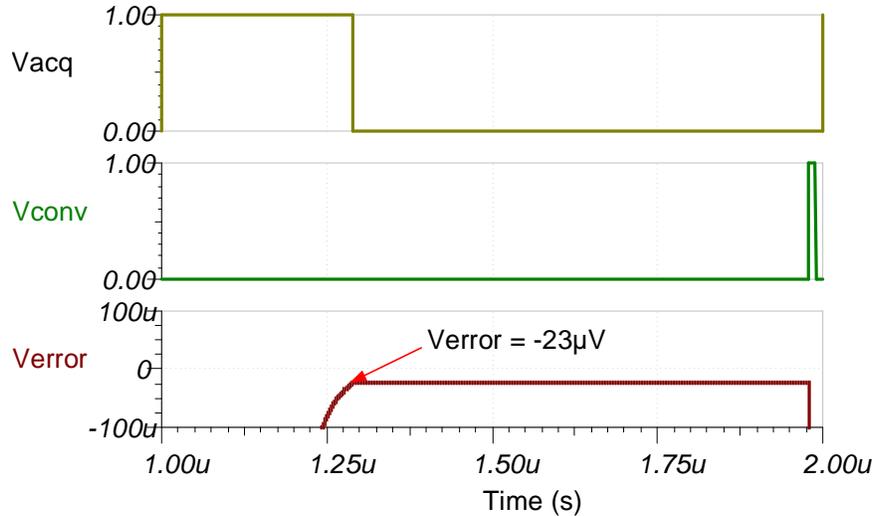
The bandwidth for this circuit is limited by the RC charge bucket circuit ( $R_{fit}$  and  $C_{fit}$ ). The hand calculation and the simulated results compare well (hand calculation  $f_c = 4.82\text{MHz}$ , simulated  $f_c = 5.08\text{MHz}$ ). See the [Op Amp Bandwidth](#) video series for more details on this subject.

$$f_c = \frac{1}{2\pi \cdot (2 \cdot 15\Omega) \cdot (1.1\text{nF})} = 4.82\text{MHz}$$



### Transient ADC Input Settling Simulation

The following simulation shows settling to a +5-V DC input signal with the OPA828 device. This type of simulation shows that the sample and hold kickback circuit is properly selected to drive ADS8860 at a 1-MSPS sampling rate and meets the desired ½ of a LSB (38.15µV). See the [Introduction to SAR ADC Front-End Component Selection](#) for detailed theory on this subject.



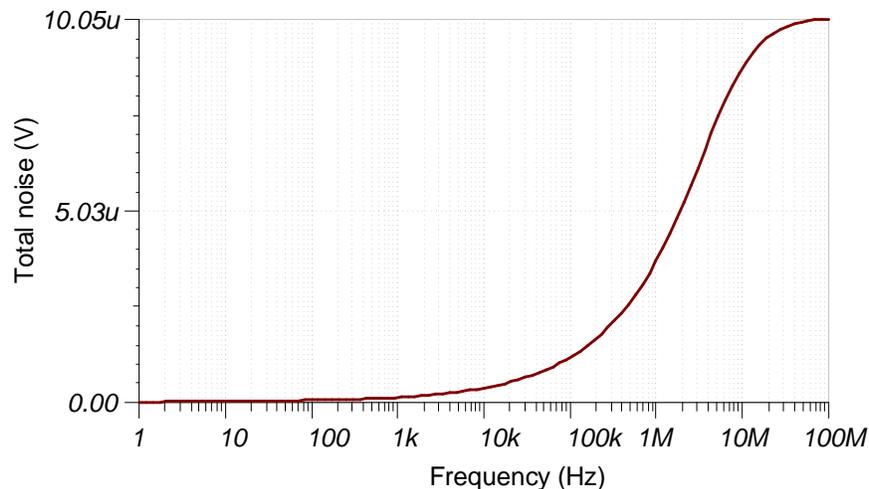
### Noise Simulation

In this circuit example, the noise is dominated by the wide band amplifier noise so the resistors do not contribute significantly. Hence, the noise from the resistors is neglected in this calculation:

$$E_n = e_{n_{828}} \cdot \sqrt{K_n \cdot f_c}$$

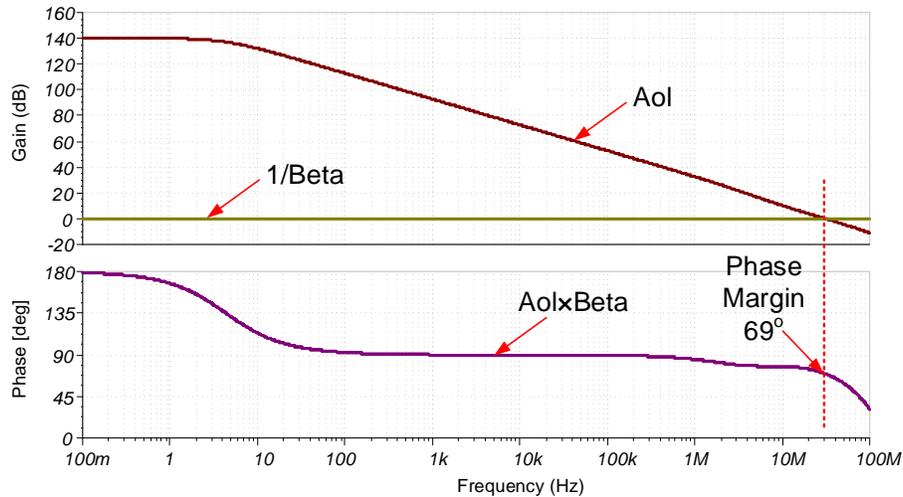
$$E_n = 4\text{nV} / \sqrt{\text{Hz}} \cdot \sqrt{1.57 \cdot 5.08\text{MHz}} = 11.3\mu\text{V}_{\text{RMS}}$$

Note that calculated and simulated match well (simulated = 10.05µV<sub>RMS</sub> as in the following graph). See [Amplifier Noise Simulations \(Op Amps: Noise 5\)](#) for detailed theory on amplifier noise calculations, and [Calculating the Total Noise for ADC Systems](#) for data converter noise.



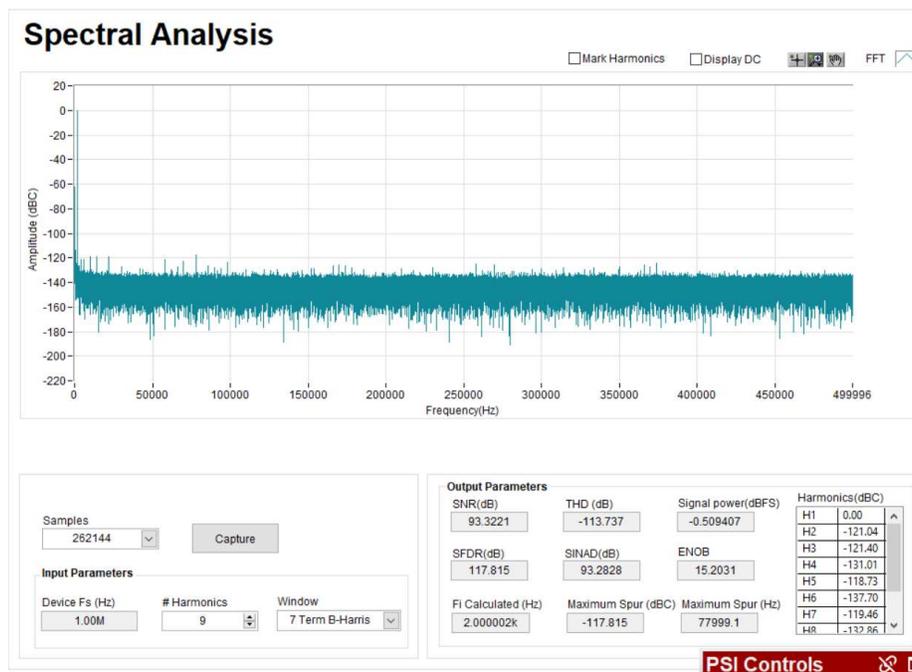
## Stability

The following simulation shows a stability check for the performance-improved solution previously shown. This design has 69 degrees of phase margin which indicates that the circuit is very stable. Generally, the circuit which has more than 45 degrees of phase margin is considered to be stable. For more information on stability analysis check the [Op Amps: Stability](#) video series.



## AC Performance Checked on Hardware

The following spectral analysis is measured using the [Precision Labs EVM \(PLABS-SAR-EVM-PDK\)](#). The AC performance including all the protection circuitry is better than the typical specifications in the [ADS8860 16-bit, 1-MSPS, Serial Interface, Micropower, Miniature, Single-Ended Input, SAR Analog-to-Digital Converter data sheet](#) (Measured SNR = 93.3dB, THD = -113.7dB, ADS8860 Typical: SNR = 92dB, THD = -108dB).



## Design Featured Devices and Alternative Parts

Device	Key Features	Link	Other Possible Devices
ADS8860	16-bit resolution, 1-MSPS sample rate, single-ended input, $V_{REF}$ input range 2.5V to 5.0V, SPI, SAR ADC	<a href="http://www.ti.com/product/ADS8860">http://www.ti.com/product/ADS8860</a>	<a href="http://www.ti.com/adcs">http://www.ti.com/adcs</a>
ADS9224R	16-bit, 3-MSPS, dual-channel, simultaneous-sampling SAR ADC with internal reference and enhanced SPI, SAR ADC	<a href="http://www.ti.com/product/ADS9224R">http://www.ti.com/product/ADS9224R</a>	<a href="http://www.ti.com/adcs">http://www.ti.com/adcs</a>
ADS8168	16-bit, 1-MSPS, 8-channel, SAR ADC with $V_{REF}$ , $V_{REF}$ buffer and multiplexer, enhanced SPI SAR ADC	<a href="http://www.ti.com/product/ADS8168">http://www.ti.com/product/ADS8168</a>	<a href="http://www.ti.com/adcs">http://www.ti.com/adcs</a>
OPA828	36-V, high-precision, low-noise, low-bias current, JFET- input operational amplifier	<a href="http://www.ti.com/product/OPA828">http://www.ti.com/product/OPA828</a>	<a href="http://www.ti.com/opamps">http://www.ti.com/opamps</a>

### Link to Key Files

TINA source files – <http://www.ti.com/lit/zip/SBAC249>.

### Other References

See [Analog Engineer's Circuit Cookbooks](#) for TI's comprehensive circuit library.

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